## NSN 5961-01-556-2008

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-556-2008 **Overall Length:** 3.620 inches **Overall Height:** 1.195 inches **Overall Width:** 0.787 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole Voltage Rating In Volts Per Characteristic: 120.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 25.00 amperes total power dissipation **Power Rating Per Characteristic:** 0.5 watts average gate power dissipation **Product Name:** (inavy)diode power module **Special Features:** Operating temperature: -40 to 125 degrees celsuis **Terminal Type And Quantity:** 2 screw Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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